

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1298

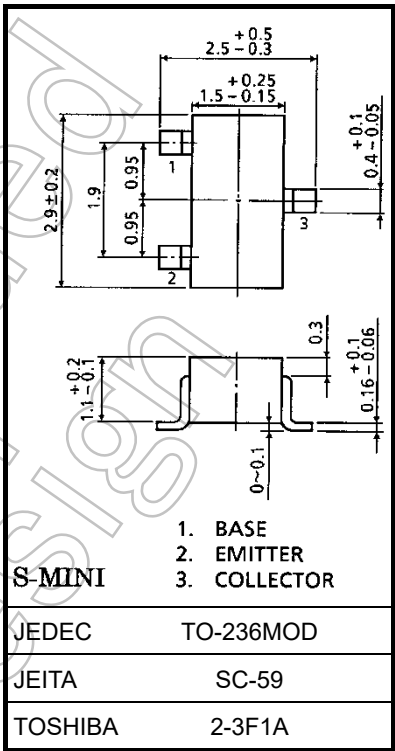
Unit: mm

Low Frequency Power Amplifier Application
Power Switching Applications

- High DC current gain: $h_{FE} = 100$ to 320
- Low saturation voltage: $V_{CE(sat)} = -0.4\text{ V (max)}$
 $(I_C = -500\text{ mA}, I_B = -20\text{ mA})$
- Suitable for driver stage of small motor
- Complementary to 2SC3265
- Small package

Absolute Maximum Ratings (Ta = 25°C)

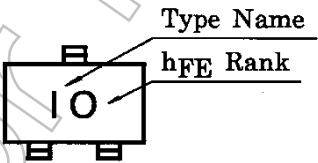
Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-30	V
Collector-emitter voltage	V_{CEO}	-25	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-800	mA
Base current	I_B	-160	mA
Collector power dissipation	P_C	200	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55 to 150	°C



Weight: 0.012 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



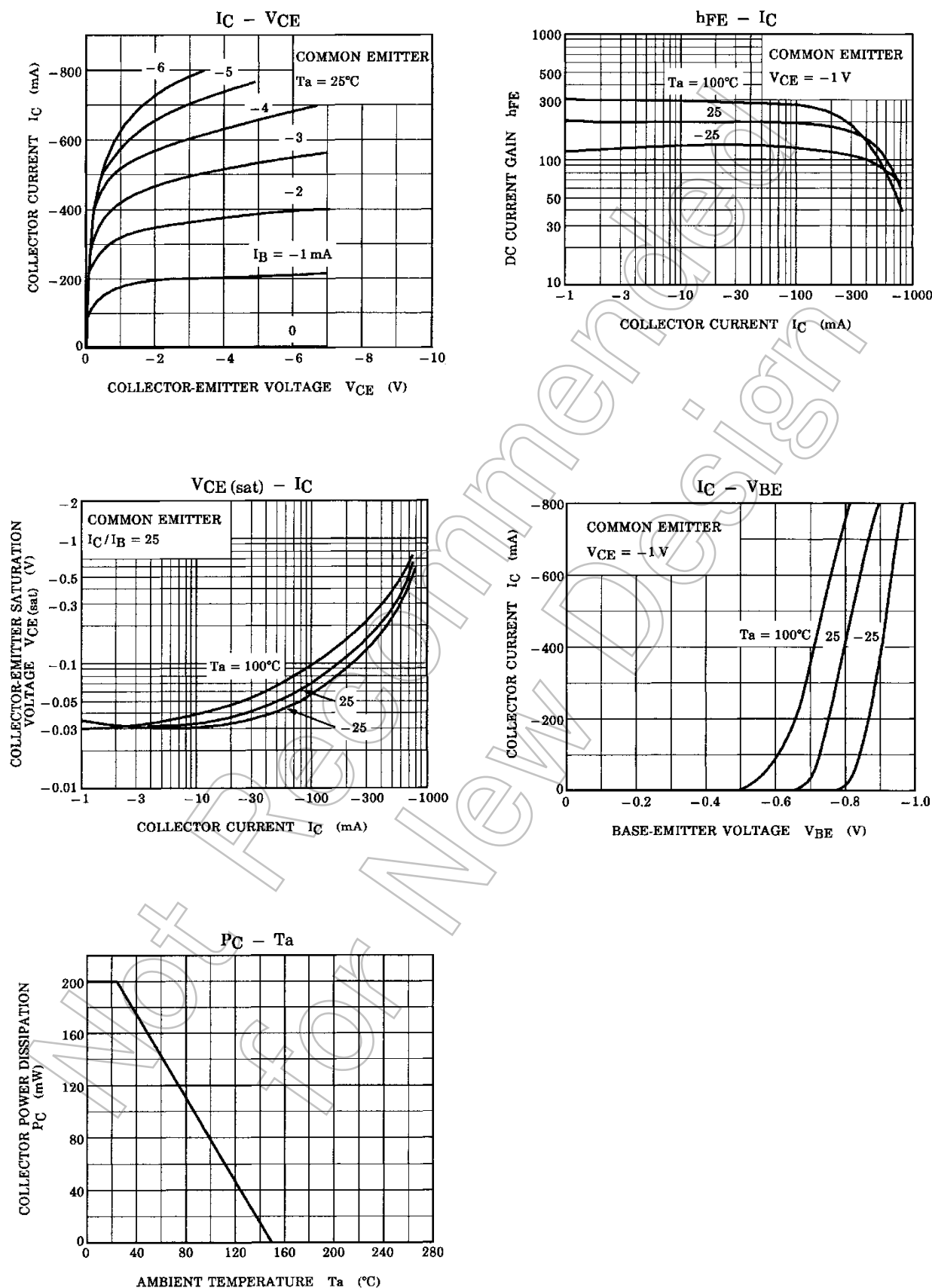
Start of commercial production
1982-10

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	ICBO	V _{CB} = -30 V, I _E = 0 mA	—	—	-0.1	μA
Emitter cut-off current	IEBO	V _{EB} = -5 V, I _C = 0 mA	—	—	-0.1	μA
Collector-emitter breakdown voltage	V _(BR) CEO	I _C = -10 mA, I _B = 0 mA	-25	—	—	V
Emitter-base breakdown voltage	V _(BR) EBO	I _E = -0.1 mA, I _C = 0 mA	-5	—	—	V
DC current gain	h _{FE} (1) (Note)	V _{CE} = -1 V, I _C = -100 mA	100	—	320	—
	h _{FE} (2)	V _{CE} = -1 V, I _C = -800 mA	40	—	—	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = -500 mA, I _B = -20 mA	—	—	-0.4	V
Base-emitter voltage	V _{BE}	V _{CE} = -1 V, I _C = -10 mA	-0.5	—	-0.8	V
Transition frequency	f _T	V _{CE} = -5 V, I _C = -10 mA	—	120	—	MHz
Collector output capacitance	C _{ob}	V _{CB} = -10 V, I _E = 0 mA, f = 1 MHz	—	13	—	pF

Note: h_{FE} (1) classification O: 100 to 200, Y: 160 to 320

Characteristics Curves (Note)



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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